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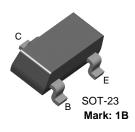


SEMICONDUCTOR®

MMBT2222

NPN General Purpose Amplifier

• Sourced from process 19.



Absolute Maximum Ratings* $T_a=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|-----------------------------------|--|-----------|-------|
| √ _{CEO} | Collector-Emitter Voltage | 30 | V |
| √ _{CBO} | Collector-Base Voltage | 60 | V |
| √ _{EBO} | Emitter-Base Voltage | 5.0 | V |
| c | Collector Current - Continuous | 0.6 | A |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | -55 ~ 150 | °C |

* This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These rating are based on a maximum junction temperature of 150 degrees C.
2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|----------------------|--|--|------|------|-------|
| Off Charac | cteristics | | | | |
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage * | $I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$ | 30 | | V |
| V _{(BR)CBO} | Collector-Base Breakdown Voltage | $I_{\rm C} = 10\mu {\rm A}, I_{\rm E} = 0$ | 60 | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | $I_{\rm E} = 10\mu A, I_{\rm C} = 0$ | 5.0 | | V |
| I _{CBO} | Collector Cutoff Current | $V_{CB} = 50V, I_{E} = 0$ | | 10 | μΑ |
| | | $V_{CB} = 50V, I_E = 0, T_a = 125^{\circ}C$ | | 10 | μΑ |
| I _{EBO} | Emitter Cutoff Current | $V_{EB} = 3.0V, I_{C} = 0$ | | 10 | nA |
| On Charac | teristics | | | | |
| h _{FE} | DC Current Gain | I _C = 0.1mA, V _{CE} = 10V | 35 | | |
| | | I _C = 1.0mA, V _{CE} = 10V | 50 | | |
| | | I _C = 10mA, V _{CE} = 10V | 75 | | |
| | | $I_{C} = 150 \text{mA}, V_{CE} = 10 \text{V}^{*}$ | 100 | 300 | |
| | | $I_{C} = 150 \text{mA}, V_{CF} = 1.0 \text{V}^{*}$ | 50 | | |
| | | $I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V}^{*}$ | 30 | | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage * | I _C = 150mA, I _B = 15V | | 0.4 | V |
| - () | | $I_{\rm C} = 500 {\rm mA}, I_{\rm B} = 50 {\rm V}$ | | 1.6 | |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 150mA, I _B = 15V | | 1.3 | V |
| . / | | I _C = 500mA, I _B = 50V | | 2.6 | |

MMBT2222

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Electrical Characteristics (Continued) T_a=25°C unless otherwise noted Symbol Parameter **Test Condition** Min. Max. Units **Small Signal Characteristics** Curent Gain Bandwidth Product $\mathsf{I}_{\mathsf{C}} = 20\mathsf{m}\mathsf{A},\,\mathsf{V}_{\mathsf{C}\mathsf{E}} = 20\mathsf{V},\,\mathsf{f} = 100\mathsf{M}\mathsf{Hz}$ 250 f_{T} $V_{CB} = 10V, I_E = 0, f = 1MHz$ **Output Capacitance** 8.0 pF C_{obo} $V_{EB} = 0.5V, I_{C} = 0, f = 1MHz$ Input Capacitance 30 pF C_{ibo} **Switching Characteristics** $V_{CC} = 30V, V_{BE(OFF)} = 0.5V, I_{C} = 150mA, I_{B1} = 15mA$ Delay Time 10 ns td **Rise Time** 25 t_r ns $V_{CC} = 30V, I_C = 150mA,$ 225 t_s Storage Time ns $I_{B1} = I_{B2} = 15 \text{mA}$ Fall Time 60 ns t_f

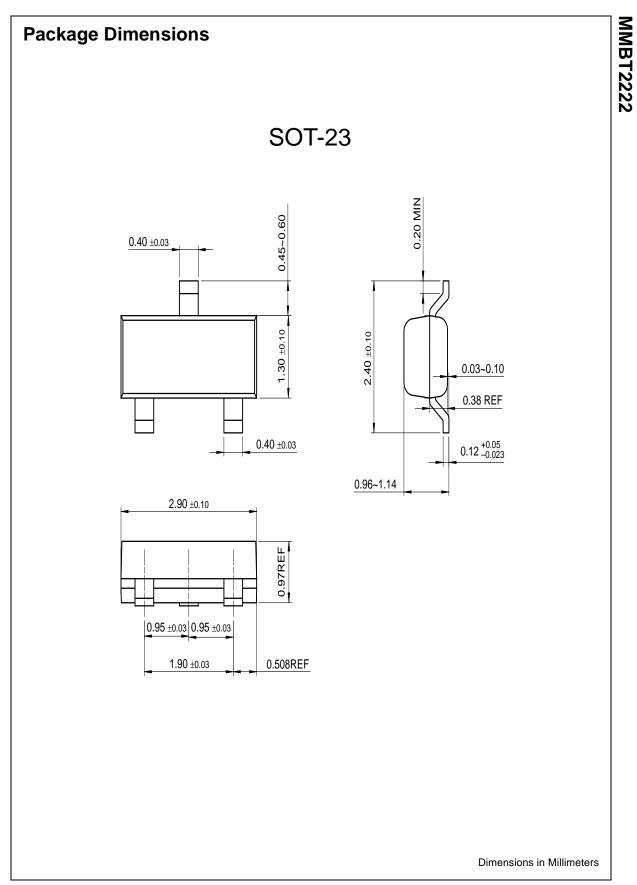
* Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%

Thermal Characteristics $T_a=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Max. | Units |
|-----------------|---|------|-------|
| PD | Total Device Dissipation | 350 | mW |
| | Derate above 25°C | 2.8 | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 357 | °C/W |

* Device mounted on FR-4PCB 1.6" \times 1.6" \times 0.06".

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|--------------------------|---------------------------|---|
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